Long wav length VCSEL				
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Inventor(s):	RAMDANI JAMAL (US); JIANG WENBIN (US); LEBBY MICHAEL S (US)			
Applicant(s)::	MOTOROLA INC (US)			
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Equivalents:	TW396668, US5943359			
Lon net drive				
Abstract				
A VCSEL for emitting long wavelength light including a GaAs (111) substrate element (12), a first mirror stack (14) with mirror pairs in a GaAs/AlGaAs material system lattice matched to a GaInAsN active region (20) with an active structure (23) sandwiched between a first cladding region (24) adjacent the first mirror stack (14) and a second cladding region (25), the active structure (23) including a nitride based quantum well (35, 36, & 37), and a second mirror stack (26) lattice matched to the second cladding region (25) and having mirror pairs in a GaAs/AlGaAs material system.				
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(71) Applicant: MOTOROLA, INC. Schaumburg, IL 60196 (US)

(72) Inventors:Ramdani, JamalGilbert, Arizona, 85233 (US)

 Lebby, Michael S. Apache Junction, Arizona 85219 (US)

 Jiang, Wenbin Phoenix, Arizona, 85044 (US)

(74) Representative:

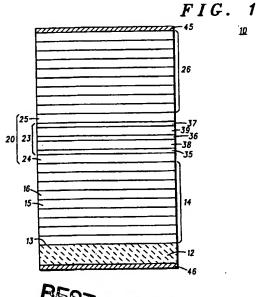
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(54) Long wavelength VCSEL

(57) A VCSEL for emitting long wavelength light including a GaAs (111) substrate element (12), a first mirror stack (14) with mirror pairs in a GaAs/AlGaAs material system lattice matched to a GalnAsN active region (20) with an active structure (23) sandwiched between a first cladding region (24) adjacent the first mirror stack (14) and a second cladding region (25), the active structure (23) including a nitride based quantum well (35, 36, & 37), and a second mirror stack (26) lattice matched to the second cladding region (25) and having mirror pairs in a GaAs/AlGaAs material system.







EUROPEAN SEARCH REPORT

Application Number

ategory	Citation of document with in of relevant pass:		Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int.CI.6)
Y	expected characteristics and service emitting lasers QUANTUM OPTOELECTROST DIGEST SERIES, POSTO	al cavity surface NICS 1997, TECHNICAL CONFERENCE EDITION, , rch 1997, page 126-128 USA	1-9	H01S3/19 H01S3/085
Y	US 5 383 211 A (VAN 17 January 1995 * column 5, line 19	DE WALLE CHRIS ET AL) -39 *	1-9	
A	KONDOW M ET AL: "A GAINAS FOR LONG-WAYD DIODES WITH EXCELLED PERFORMANCE" INTERNATIONAL CONFE DEVICES AND MATERIA 21 August 1995, pag XP000544869 * the whole documen	ELENGTH-RANGE LASER NT HIGH-TEMEPRATURE RENCE ON SOLID STATE LS, es 1016-1018,	1-9	TECHNICAL FIELDS SEARCHED (Int.Ci.6) H01S
Α	EP 0 723 303 A (HEW July 1996 + the whole documen		1-9	
	The present search report has I	been drawn up for all claims		
	Place of search THE HAGUE	Date of completion of the search	63	Examiner
X:par Y:par doc A:tec O:no	THE HAGUE CATEGORY OF CITED DOCUMENTS tlicularly relevant if taken alone ticularly relevant if combined with anot ument of the same category hnological background n-written disclosure smediate document	T: theory or princip E: earlier patent do after the filing da D: document cited L: document cited a: member of the s document	le underlying the current, but pub- ite in the application or other reasons	lished on, or